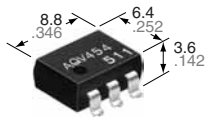
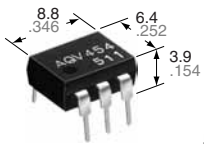


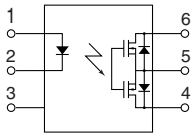
Panasonic
ideas for life

**High sensitivity and low on-resistance.
DIP (1 Form B) 6-pin type.**

**HE PhotoMOS
(AQV450, AQV454H)**



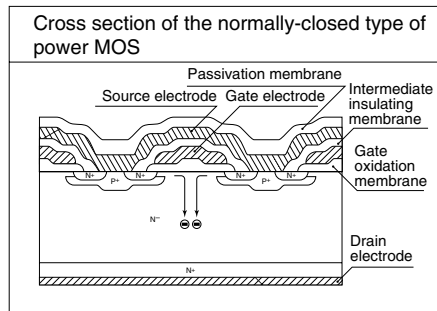
mm inch



FEATURES

1. Form B (Normally-closed) type

Has been realized thanks to the built-in MOSFET processed by our proprietary method, DSD (Double-diffused and Selective Doping) method.



2. Controls low-level analog signals

PhotoMOS relays feature extremely low closed-circuit offset voltage to enable control of low-level analog signals without distortion.

3. High sensitivity, low ON resistance

Can control a maximum 0.15 A load current with a 5 mA input current. Low ON resistance of 16 Ω (AQV454). Stable operation because there are no metallic contact parts.

4. Controls various types of load such as relays, motors, lamps and solenoids.

5. Eliminates the need for a power supply to drive the power MOSFET

A power supply used to drive the power MOSFET is unnecessary because of the built-in optoelectronic device. This results in easy circuit design and small PC board area.

6. Low thermal electromotive force (Approx. 1 μ V) (Basic insulation)

7. Reinforced insulation 5,000 V type also available.

More than 0.4 mm .016 inch internal insulation distance between inputs and outputs. Conforms to IEC950 (reinforced insulation).

RoHS Directive compatibility information
<http://www.mew.co.jp/ac/e/environment/>

TYPICAL APPLICATIONS

- Security equipment
- High-speed inspection machines
- Measuring instruments
- Telephone equipment
- Sensors

TYPES

Type	I/O isolation	Output rating*		Part No.				Packing quantity	
		Load voltage	Load current	Through hole terminal	Surface-mount terminal			Tube	Tape and reel
				Tube packing style	Tape and reel packing style				
				Picked from the 1/2/3-pin side		Picked from the 4/5/6-pin side			
AC/DC	1,500 V AC	250 V	200 mA	AQV453	AQV453A	AQV453AX	AQV453AZ	1 tube contains 50 pcs. 1 batch contains 500 pcs.	1,000 pcs.
				AQV454	AQV454A	AQV454AX	AQV454AZ		
	Reinforced 5,000 V AC	400 V	150 mA	AQV454H	AQV454HA	AQV454HAX	AQV454HAZ		

* Indicate the peak AC and DC values.

Note: For space reasons, the SMD terminal shape indicator "A" and the package style indicator "X" or "Z" are not marked on the relay.

RATING

1. Absolute maximum ratings (Ambient temperature: 25°C 77°F)

Item		Symbol	Type of connection	AQV453(A)	AQV454(A)	AQV454H(A)	Remarks	
Input	LED forward current	I_F		50 mA			f = 100 Hz, Duty factor = 0.1%	
	LED reverse voltage	V_R		5 V				
	Peak forward current	I_{FP}		1 A				
	Power dissipation	P_{in}		75 mW				
Output	Load voltage (peak AC)	V_L		250 V	400 V		A connection: Peak AC, DC B,C connection: DC	
	Continuous load current	I_L		A	0.2 A	0.15 A		
				B	0.3 A	0.18 A		
				C	0.4 A	0.25 A		
	Peak load current	I_{PEAK}			0.6 A	0.5 A		A connection: 100 ms (1 shot), $V_L = DC$
Power dissipation	P_{OUT}		360 mW					
Total power dissipation		P_T		410 mW				
I/O isolation voltage		V_{iso}		1,500 V AC		5,000 V AC		
Temperature limits	Operating	T_{opr}		-40°C to +85°C -40°F to +185°F			Non-condensing at low temperatures	
	Storage	T_{stg}		-40°C to +100°C -40°F to +212°F				

2. Electrical characteristics (Ambient temperature: 25°C 77°F)

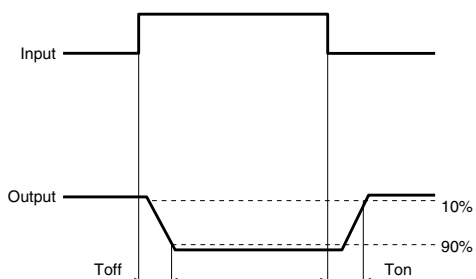
Item			Symbol	Type of connection	AQV453(A)	AQV454(A)	AQV454H(A)	Remarks	
Input	LED operate (OFF) current	Typical	I_{Foff}	—	1 mA	0.9 mA	1.4 mA	$I_L = \text{Max.}$	
		Maximum			3 mA				
	LED reverse (ON) current	Minimum	I_{Fon}	—	0.4 mA			$I_L = \text{Max.}$	
		Typical			0.9 mA	0.8 mA	1.3 mA		
LED dropout voltage	Typical	V_F	—	1.25 V (1.14 V at $I_F=5 \text{ mA}$)			$I_F = 50 \text{ mA}$		
	Maximum			1.5 V					
Output	On resistance	Typical	R_{on}	A	5.5 Ω	12.4 Ω		$I_F = 0 \text{ mA}$ $I_L = \text{Max.}$ Within 1 s on time	
		Maximum			8 Ω	16 Ω			
		Typical	R_{on}	B	2.7 Ω	6.2 Ω		$I_F = 0 \text{ mA}$ $I_L = \text{Max.}$ Within 1 s on time	
		Maximum			4 Ω	8 Ω			
		Typical	R_{on}	C	1.4 Ω	3.1 Ω		$I_F = 0 \text{ mA}$ $I_L = \text{Max.}$ Within 1 s on time	
		Maximum			2 Ω	4 Ω			
Off state leakage current	Maximum	I_{Leak}	—	1 μA	1 μA	10 μA	$I_F = 5 \text{ mA}$ $V_L = \text{Max.}$		
Transfer characteristics	Switching speed	Operate (OFF) time*	Typical	T_{off}	—	1.52 ms	1.2 ms	1.8 ms	$I_F = 0 \text{ mA} \rightarrow 5 \text{ mA}$ $I_L = \text{Max.}$
			Maximum			3 ms	2.0 ms	3.0 ms	
		Reverse (ON) time*	Typical	T_{on}	—	0.4 ms	0.36 ms	0.4 ms	$I_F = 5 \text{ mA} \rightarrow 0 \text{ mA}$ $I_L = \text{Max.}$
			Maximum			1 ms			
	I/O capacitance	Typical	C_{iso}	—	1.3 pF			f = 1 MHz $V_B = 0 \text{ V}$	
Maximum	3 pF								
Initial I/O isolation resistance	Minimum	R_{iso}	—	1,000 M Ω			500 V DC		

Note: Recommendable LED forward current.

Standard type: $I_F = 5 \text{ mA}$ Reinforced type: $I_F = 5 \text{ to } 10 \text{ mA}$

*Operate/Reverse time

For type of connection.



■ For Dimensions.
 ■ For Schematic and Wiring Diagrams.
 ■ For Cautions for Use.

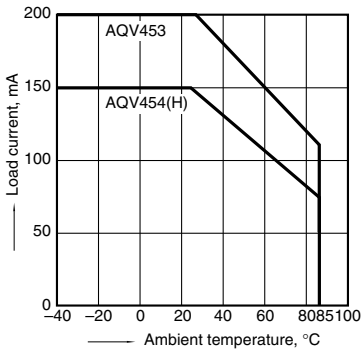
HE PhotoMOS (AQV450, AQV454H)

REFERENCE DATA

1. Load current vs. ambient temperature characteristics

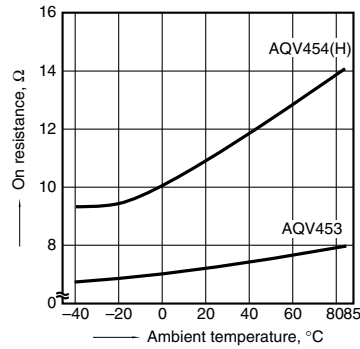
Allowable ambient temperature: -40°C to +85°C
-40°F to +185°F

Type of connection: A



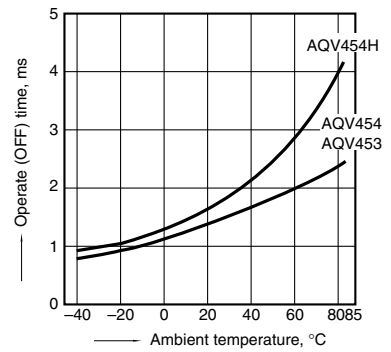
2. On resistance vs. ambient temperature characteristics

Measured portion: between terminals 4 and 6;
LED current: 0 mA; Load voltage: Max. (DC);
Continuous load current: Max. (DC)



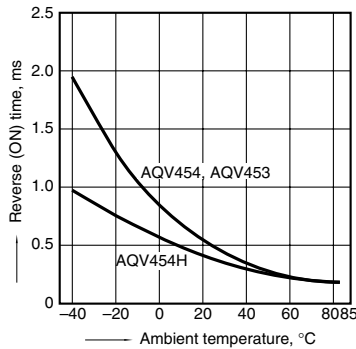
3. Operate (OFF) time vs. ambient temperature characteristics

LED current: 5 mA; Load voltage: Max. (DC);
Continuous load current: Max. (DC)



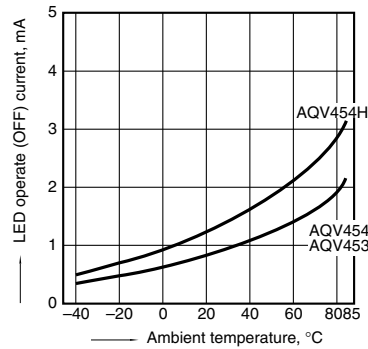
4. Reverse (ON) time vs. ambient temperature characteristics

LED current: 5 mA; Load voltage: Max. (DC);
Continuous load current: Max. (DC)



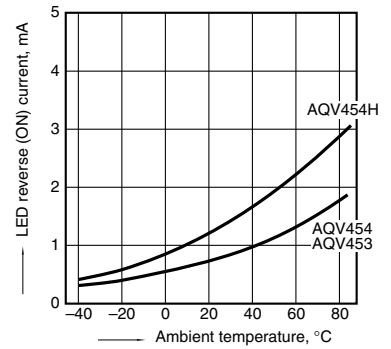
5. LED operate (OFF) current vs. ambient temperature characteristics

Load voltage: Max. (DC);
Continuous load current: Max. (DC)



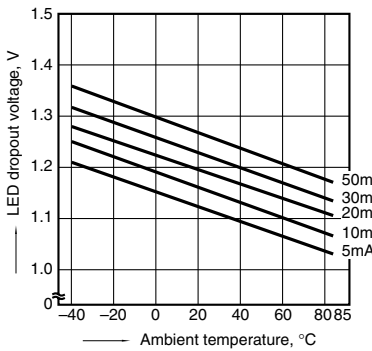
6. LED reverse (ON) current vs. ambient temperature characteristics

Load voltage: Max. (DC);
Continuous load current: Max. (DC)



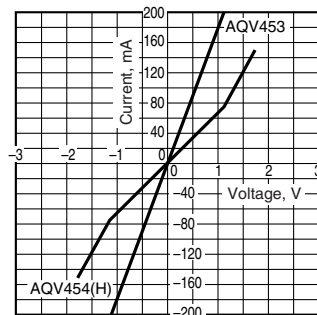
7. LED dropout voltage vs. ambient temperature characteristics

LED current: 5 to 50 mA



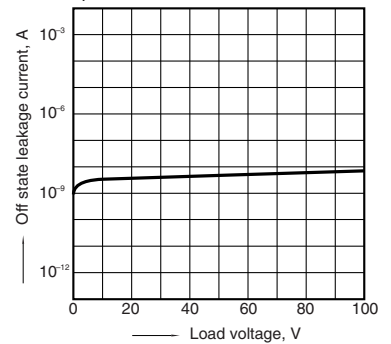
8. Current vs. voltage characteristics of output at MOS portion

Measured portion: between terminals 4 and 6;
Ambient temperature: 25°C 77°F



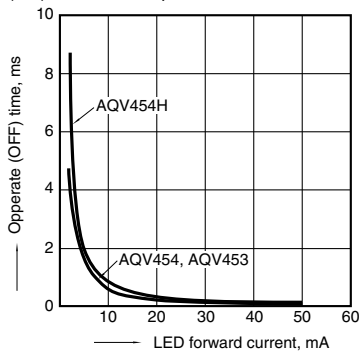
9. Off state leakage current vs. load voltage characteristics

Sample: AQV454;
Measured portion: between terminals 4 and 6;
Ambient temperature: 25°C 77°F



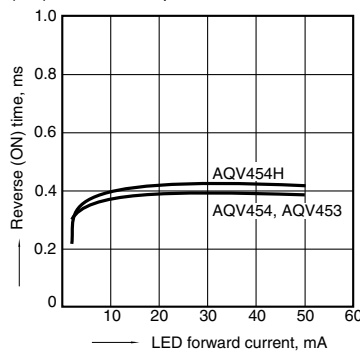
10. Operate (OFF) time vs. LED forward current characteristics

Measured portion: between terminals 4 and 6;
Load voltage: Max. (DC); Continuous load current: Max. (DC); Ambient temperature: 25°C 77°F



11. Reverse (ON) time vs. LED forward current characteristics

Measured portion: between terminals 4 and 6;
Load voltage: Max. (DC); Continuous load current: Max. (DC); Ambient temperature: 25°C 77°F



12. Output capacitance vs. applied voltage characteristics

Measured portion: between terminals 4 and 6;
Frequency: 1 MHz; Ambient temperature: 25°C 77°F

